

January 1998

NOT RECOMMENDED FOR NEW DESIGNS
 See HI-565A

12-Bit High Speed Monolithic D/A Converter

Features

- Output Current 2mA, F.S.
- Monolithic Construction
- Extremely Fast Settling 300ns to 0.01% (Typ)
- Low Gain Drift $\pm 10\text{ppm}/^\circ\text{C}$ (Max)
- Linearity Guaranteed Over Temperature $\pm 1/2$ LSB (Max)
- Designed for Minimum Glitches
- Monotonic Over Temperature

Applications

- CRT Display Generation
- High Speed A/D Converters
- Video Signal Reconstruction
- Waveform Synthesizers
- High Speed Data Acquisition
- High-Rel Applications
- Precision Instruments

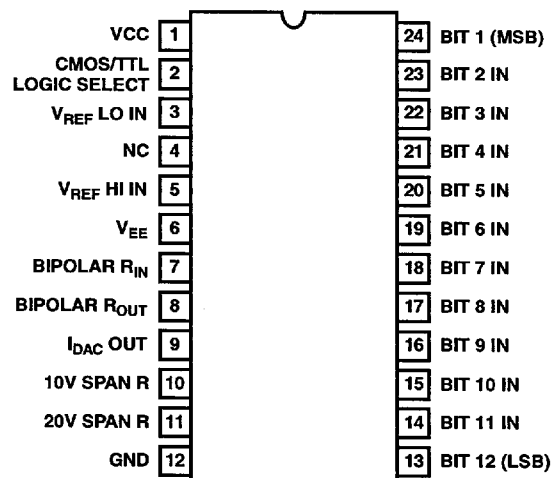
Description

The Harris HI-562A is the first monolithic digital-to-analog converter to combine both high speed performance and 12-bit accuracy on the same chip. The HI-562A's fast output current settling of 300ns to 0.01% is achieved using Dielectric Isolation processing to reduce internal parasitics for fast rise and fall times during switching. Output glitches are minimized in the HI-562A by incorporating equally weighted current sources switched into an R-2R ladder network for symmetrical turn-ON and turn-OFF switching times. This creates within the chip a very uniform and constant thermal distribution for excellent linearity and also completely eliminates thermal transients during switching. High stability thin film resistor processing together with laser trimming provide the HI-562A with guaranteed 12-bit linearity to within $\pm 1/2$ LSB maximum at $+25^\circ\text{C}$ for -4 and -5 parts and to within $\pm 1/4$ LSB maximum at $+25^\circ\text{C}$ for -2 and -8 parts. The HI-562A is recommended as a replacement for higher cost hybrid and modular units for increased reliability and accuracy in applications such as CRT displays, precision instruments and data acquisition systems requiring throughput rates as high as 3.3MHz for full range transitions. Its small size makes it an ideal choice as the heart of high speed A/D converter designs or as a building block in high speed or high resolution industrial process control systems. The HI-562A is also ideally suited for aircraft and space instrumentation where operation over a wide temperature range is required.

The HI-562A is offered in commercial, industrial and military grades. The HI-562A is available in a 24 lead Ceramic Side-braze DIP. For MIL-STD-883 compliant parts, request the HI-562A/883 data sheet.

Pinout

HI562A (SIDEBRAZE CDIP)
 TOP VIEW



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper I.C. Handling Procedures.

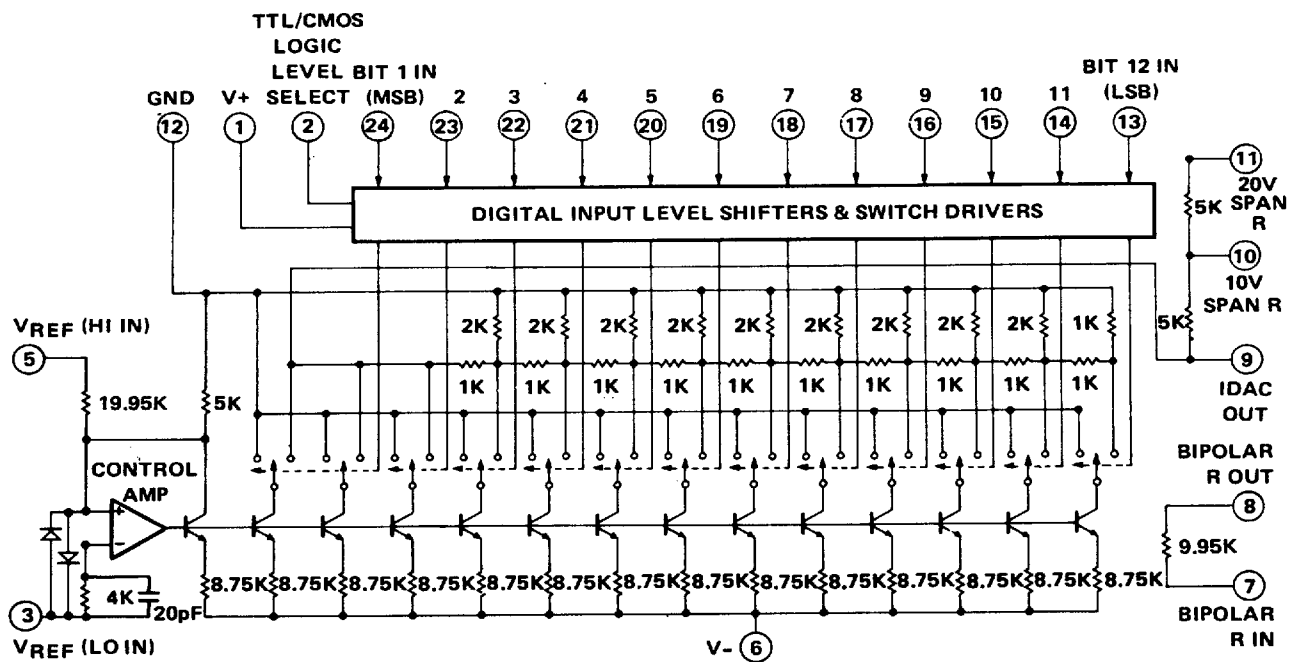
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Functional Diagram



NOTE: Pin Numbers Refer to DIP Package Only.

Specifications HI-562A

HI-562A

Absolute Maximum Ratings (Referred to GND, Note 1)

Power Supply Inputs	
V_{ps+}	+20V
V_{ps-}	-20V
Reference Inputs	
V_{REF} (High)	$\pm 16.5V$
Digital Inputs	
Bits 1-12 (TTL)	-1V, +7.5V
Bits 1-12 (CMOS)	-1V, V_{ps+}
CMOS/TTL Logic Select	-1V, +16.5V
Outputs	
Pins 7, 8, 10, 11	$\pm V_{ps}$
Pin 9	$+V_{ps}, -5V$
Junction Temperature	+175°C

Operating Temperature Range

HI-562A-2	-55°C to +125°C
HI-562A-4	-25°C to +85°C
HI-562A-5	0°C to +75°C
Storage Temperature Range	-65°C to +150°C

Electrical Specifications (@ +25°C, $V_{ps+} = +5V$, $V_{ps-} = -15V$, $V_{REF} = +10V$, CMOS/TTL Logic Select = GND, Unless Otherwise Specified.)

PARAMETER	CONDITION	HI-562A-2			HI-562A-4/HI-562A-5			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
INPUT CHARACTERISTICS								
Digital Inputs (Note 3)	Bit ON "Logic 1" Bit OFF "Logic 0"	2.0						
TTL/ CMOS	(Vps+ <9.5V) Pin 2 Tied to Pin 12 Over Full Temperature Range			0.8		2.0		0.8
CMOS	Input Voltage Logic "1" Logic "0" Input Current Logic "1" Logic "0"	0.7Vps+		0.3Vps+	0.7Vps+		0.3Vps+	V V nA μA
	Pin 2 Tied to Pin 1 (Vps+ ≥ +9.5V) Over Full Temperature Range	20 -50	±500 -100		20 50	±500 -100		
Reference Input Input Resistance Input Voltage	(±20%)		19.95K +10			19.95K +10		Ω V
TRANSFER CHARACTERISTICS								
Resolution	Over Full Temperature Range			12			12	Bits
Nonlinearity (Note 3)	@ +25°C Over Full Temperature Range		±1/2	±1/4 ±1		±1/4	±1/2 ±1	LSB LSB
Differential Nonlinearity (Note 3)	@ +25°C Over Full Temperature Range			±1/4		±1/4	±1/2	LSB
MONOTONICITY GUARANTEED								
Relative Accuracy (Note 6) Gain Error Bipolar Offset Error Unipolar Offset Error	With 50Ω (1%) Resistors All Bits ON All Bits OFF All Bits OFF		±0.024 ±0.024 ±0.012	±0.25 ±0.25 ±0.05		±0.024 ±0.024 ±0.012	±0.25 ±0.25 ±0.05	%FSR %FSR %FSR (Note 4)
Adjustment Range Gain Bipolar Offset	See Operating Instructions With 100Ω Trim Potentiometers		±0.3 ±0.6			±0.3 ±0.6		%FSR %FSR
Temperature Stability	Drift Specified With Internal Span Resistors For Volt. Output Over Full Temperature Range Over Full Temperature Range All Bits OFF All Bits OFF Over Full Temperature Range		±6 ±1	±10 ±2 ±4 ±2			±10 ±2 ±4 ±2	ppm of FSR/°C ppm of FSR/°C ppm of FSR/°C
Settling Time (Note 3) to ±1/2LSB	All Bits ON-to-OFF or OFF-to-ON		300	400		300	400	ns

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7.5%

Specifications HI-562A

HI-562A

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Electrical Specifications (Continued)

PARAMETER	CONDITIONS	HI-562A-2			HI-562A-4/HI-562A-5			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
Major Carry Transient Peak Amplitude Settling Time to 90% Complete	From 011...1 to 100...0 or 100...0 to 011...1		0.7 35			0.7 35		mA ns
Power Supply Sensitivity (Note 3)								
Unipolar Offset	All Bits OFF		±0.5			±0.5		ppm of FSR/ %V _{ps} ppm of FSR/ %V _{ps} ppm of FSR/ %V _{ps}
V _{ps+} @ +5V or +15V	"		±0.5			±0.5		
V _{ps-} @ -15V								
Bipolar Offset	All Bits OFF, Bipolar Mode		±1.5			±1.5		
V _{ps+} @ +5V or +15V	"		±1.5					
V _{ps-} @ -15V								
Gain	All Bits ON			±3.5 ±7.5			±3.5 ±7.5	
V _{ps+} @ +5V or +15V								
V _{ps-} @ -15V								
OUTPUT CHARACTERISTICS								
Output Current								
Unipolar		-1.6	-2.0	-2.4	-1.6	-2.0	-2.4	mA
Bipolar		±0.8	±1.0	±1.2	±0.8	±1.0	±1.2	mA
Resistance			2K			2K		Ω
Capacitance			20			20		pF
Output Voltage Ranges								
Unipolar	Using External Op Amp and Internal Scaling Resistors. See Figure 1 and Table 1 For Connections		0 to +5 0 to +10			0 to +5 0 to +10		V V
			±2.5			±2.5		V
			±5			±5		V
			±10			±10		V
Bipolar								
Compliance Limit (Note 3)		-3		+10	-3		+10	V
Compliance Voltage (Note 3)	Over Full Temperature Range		±1.0			±1.0		V
Output Noise	0.1 to 10Hz (All Bits ON) 0.1 to 5MHz (All Bits ON)		30 100			30 100		μV _{p-p} μV _{p-p}
POWER REQUIREMENTS								
V _{ps+} (Note 7)	Over Full Temperature Range	4.5	5	16.5	4.75	5	16.5	V
V _{ps-}	Over Full Temperature Range	-13.5	-15	-16.5	-13.5	-15	-16.5	V
I _{ps+} (Note 5)	All Bits ON or OFF in Either		8	15		8	15	mA
I _{ps-} (Note 5)	TTL or CMOS Mode (25°C)		16	23		16	23	mA
I _{ps+} (Note 5)	Same as Above Except		11	20		11	20	mA
I _{ps-} (Note 5)	Over Full Temperature Range		20	30		20	30	mA
Power Dissipation (25°C)	V _{ps+} = +5V, V _{ps-} = -15V		280	420		280	420	mW

NOTES:

- Absolute maximum ratings are limiting values, applied individually, beyond which the serviceability of the circuit may be impaired. Functional operation under any of these conditions is not necessarily implied.
- V_{ps+} tolerance is $\pm 10\%$ for HI-562A-2, and $\pm 5\%$ for HI-562A-4, -5.
- See Definitions.
- FSR is "Full Scale Range" and is 20V for $\pm 10V$ ranges, 10V for $\pm 5V$ ranges, etc., or 2mA ($\pm 20\%$) for current output.
- After 30 seconds warm-up.
- Using an external op amp with internal span resistors and specified external trim resistors in place of potentiometers R1 and R2. Errors are adjustable to zero using R1 and R2 potentiometers. (See Operating Instructions Figure 2.)
- The HI-562A is designed for $V_{ps+} = 5V$, but $+4.5V \leq V_{ps+} \leq 16.5V$ may be connected if convenient (For V_{ps+} above +5V, there is an increase in power dissipation but little change in performance.)

Die Characteristics

Transistor Count	150
Die Dimensions	103 x 209 mils
Thermal Impedance ($^{\circ}C/W$)	θ_{ja} θ_{jc}
Sidebrazed DIP	50 15
Ceramic LCC	81 40
Tie Substrate to	V_{REF} Low (Analog Ground)
Process	Bipolar-DI

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75%

Definitions of Specifications

Digital Inputs

The HI-562A accepts digital input codes in binary format and may be user connected for any one of three binary codes: Straight Binary, Two's Complement, or Offset Binary (see Operating Instructions).

DIGITAL INPUT	ANALOG OUTPUT		
	Straight Binary	Offset Binary	Two's Complement*
MSB LSB			
000...000	Zero	-FS (Full Scale)	Zero
100...000	1/2 FS	Zero	-FS
111...111	+FS - 1 LSB	+FS - 1 LSB	1/2 FS - 1 LSB
011...111	1/2 FS - 1 LSB	Zero - 1 LSB	+FS - 1 LSB
*Invert MSB with external inverter to obtain Two's Complement Coding			

Accuracy

INTEGRAL NONLINEARITY — The maximum deviation of the actual transfer characteristic from an ideal straight line. The ideal line is positioned according to "end-point linearity" for D/A converter products from Harris Semiconductor, i.e. the line is drawn between the end-points of the actual transfer characteristic (codes 00...0 and 11...1).

DIFFERENTIAL NONLINEARITY — The difference between one LSB and the output voltage change corresponding to any two consecutive codes. A Differential Nonlinearity of ± 1 LSB or less guarantees monotonicity.

MONOTONICITY — The property of a D/A converter's transfer function which guarantees that the output derivative will not change sign in response to a sequence of increasing (or decreasing) input codes. That is, the only output response to a code change is to remain constant, increase for increasing code, or decrease for decreasing code.

Settling Time

That interval between application of a digital step input, and final entry of the analog output within a specified window about the settled value. Harris Semiconductor usually specifies a unipolar 10V full scale step, to be measured from 50% of the input digital transition, and a window of $\pm 1/2$ LSB about the final value. The device output is then rated according to the worst (longest settling) case: low to high, or high to low.

Drift

GAIN DRIFT — The change in full scale analog output over the specified temperature range expressed in parts per million of full scale range per $^{\circ}\text{C}$ (ppm of FSR/ $^{\circ}\text{C}$). Gain error is measured with respect to $+25^{\circ}\text{C}$ at high (T_H) and low (T_L) temperatures. Gain drift is calculated for both high ($T_H - 25^{\circ}\text{C}$) and low ($+25^{\circ}\text{C} - T_L$) ranges by dividing the gain error by the respective change in temperature. The specification is the larger of the two representing worst case drift.

OFFSET DRIFT — The change in analog output with all bits OFF over the specified temperature range expressed in parts per million of full scale range per $^{\circ}\text{C}$ (ppm of FSR/ $^{\circ}\text{C}$). Offset error is measured with respect to $+25^{\circ}\text{C}$ at high (T_H) and low (T_L) temperatures. Offset Drift is calculated for both high ($T_H - 25^{\circ}\text{C}$) and low ($+25^{\circ}\text{C} - T_L$) ranges by dividing the offset error by the respective change in temperature. The specification given is the larger of the two, representing worst-case drift.

Power Supply Sensitivity

Power Supply Sensitivity is a measure of the change in gain and offset of the D/A converter resulting from a change in -15V , $+5\text{V}$ or $+15\text{V}$ supplies. It is specified under DC conditions and expressed as parts per million of full scale range per percent of change in power supply (ppm of FSR/%Vps).

Compliance

Compliance Voltage is the maximum output range for which specified accuracy limits are guaranteed. Compliance Limit implies functional operation only and makes no claims to accuracy.

Glitch

A glitch on the output of a D/A converter is a large transient spike resulting from unequal internal ON-OFF switching times. Worst case glitches usually occur at half-scale or the major carry code transition from 011...1 to 100...0 or vice versa. For example, if turn ON is greater than turn OFF for 011...1 to 100...0, an intermediate state of 000...0 exists, such that, the output momentarily glitches toward zero output. Matched switching times and fast switching will reduce glitches considerably.

